BIRD95 and BIRD98 Simulations

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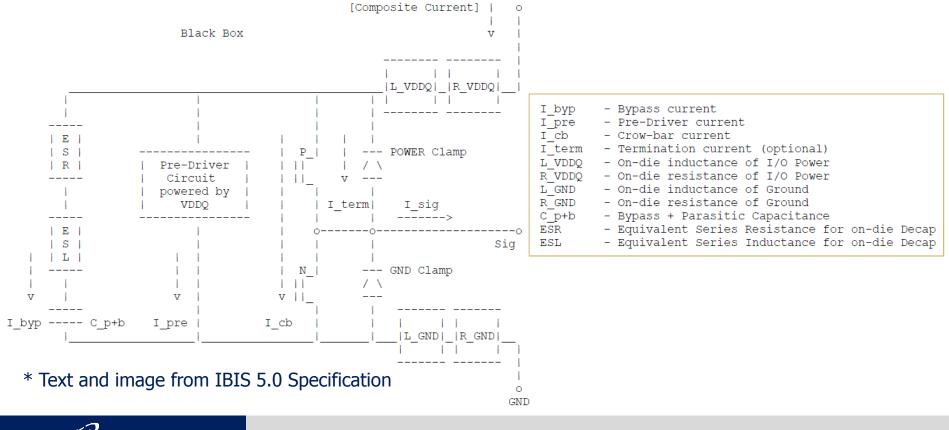
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Introduction

- [Composite Current] table data added to IBIS 5.0 through BIRD95.
- [ISSO PD] and [ISSO PU] table data added to IBIS 5.0 through BIRD98.
- Simulation done with two tools (available to authors) that include full/partial support for BIRD95 and BIRD98 in current releases.
- IBIS 5.0 DDR3 model developed and used to compare simulation tools to golden SPICE model results.

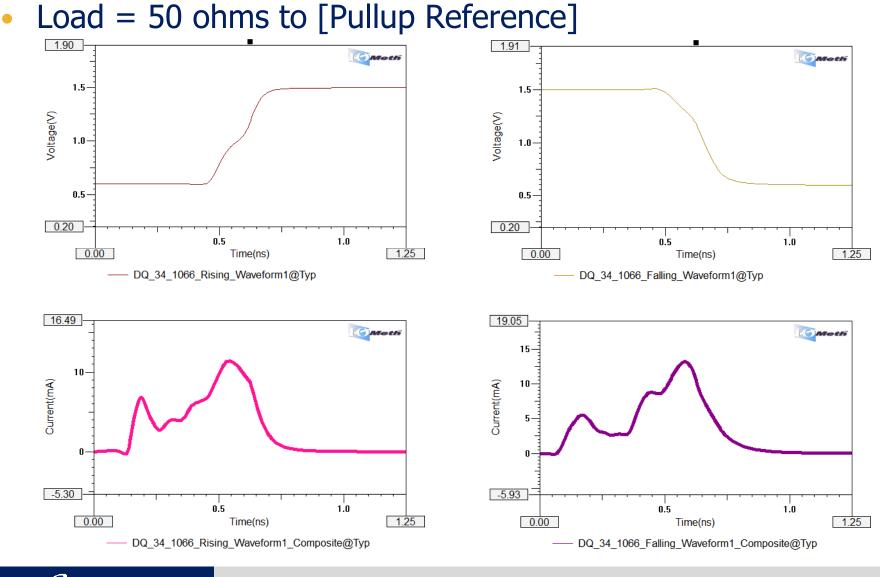
[Composite Current]

- Describes the shape of the rising and falling edge current waveforms from the power reference terminal of the buffer*.
- Adds pre-driver current I-t data.



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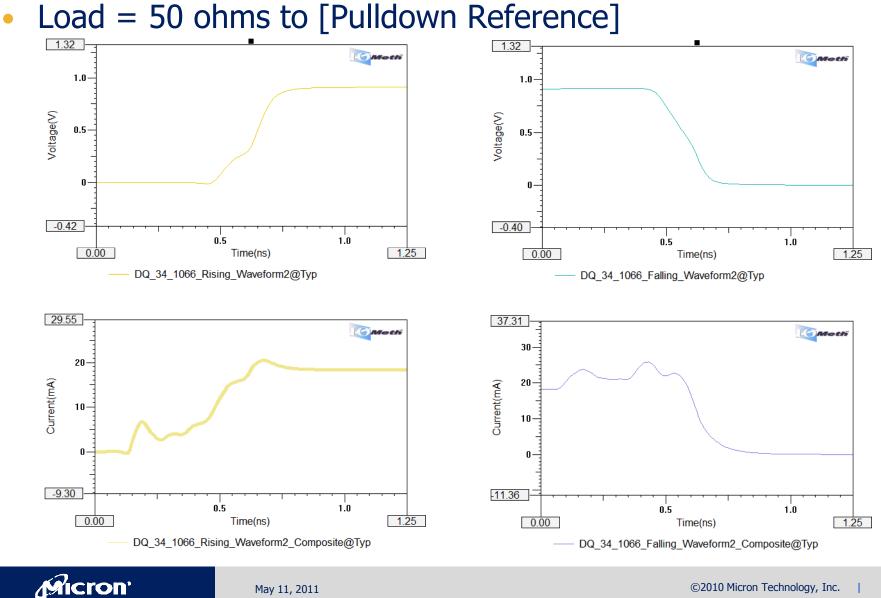
[Composite Current] Data



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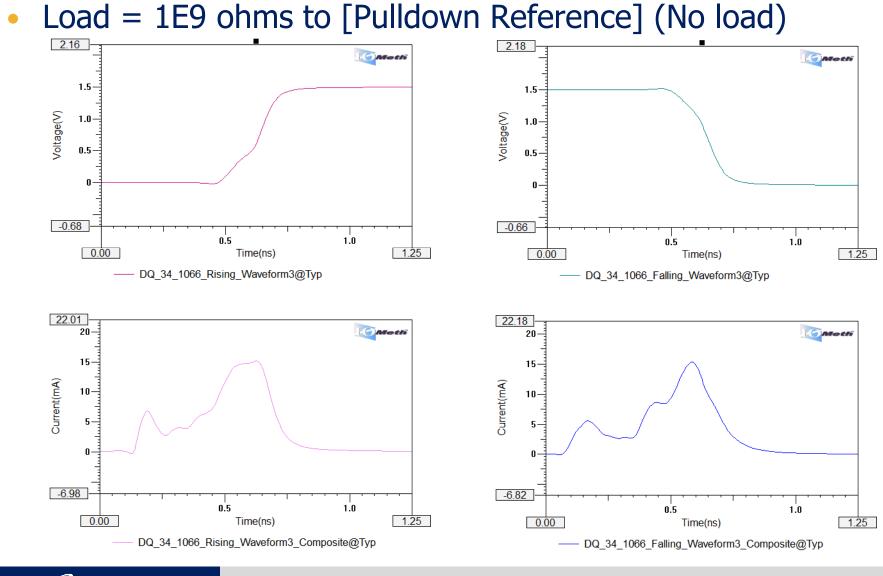
[Composite Current] Data



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[Composite Current] Data



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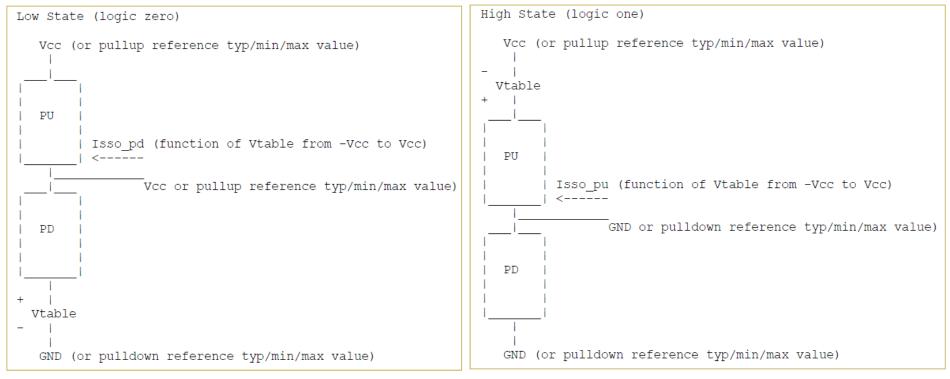
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[Composite Current] Observations

- Significant 'dead time' must be added to beginning of V-t curves to correlate with time of pre-driver current.
 - This limits model switching rate encourages overclocking.
 - Example model originally DDR3-1066, now DDR3-800.
- [Composite Current] only includes [Pullup Reference] supply current.
 - Algorithms can only assume that [Pulldown Reference] current is equal to [Pullup Reference] current.
 - Is this valid?

[ISSO PU] & [ISSO PD]

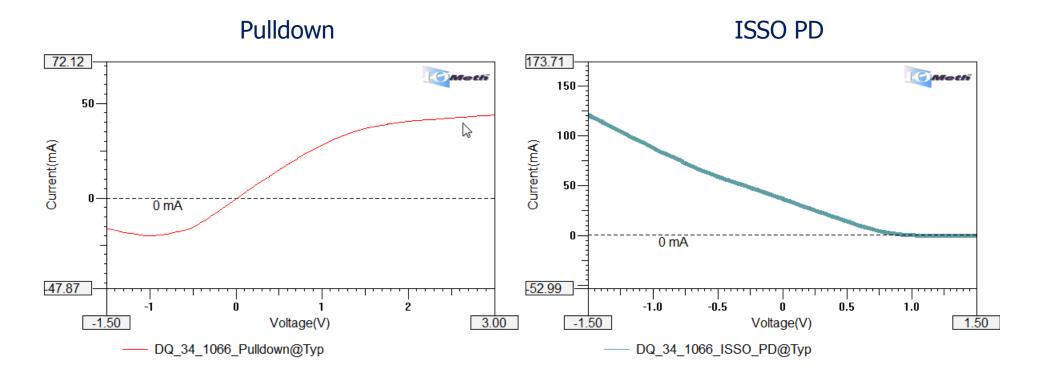
- Data tables define the effective current of the pullup/pulldown structures of a buffer as a function of the voltage on the pullup/pulldown reference nodes*.
- Adds modeling of the gate modulation effect on driver current (I_{DS} vs. V_{GS}).



* Text and image from IBIS 5.0 Specification

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[ISSO PD] Data

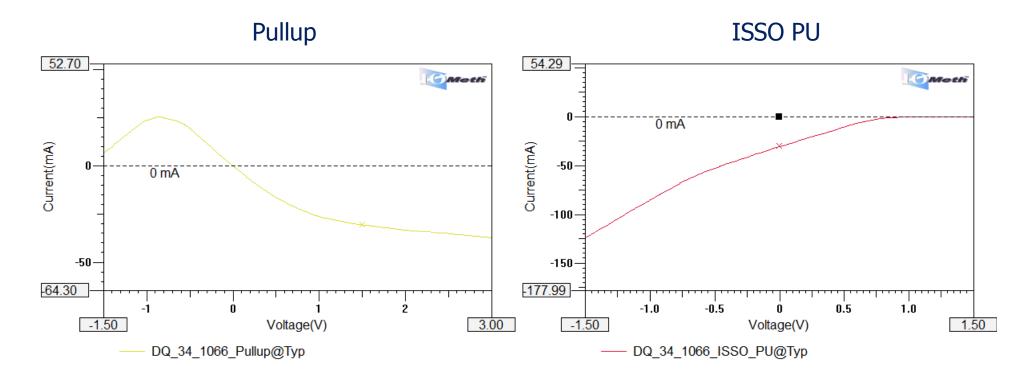


Name: DQ_34_1066_Pulldown@Typ Type: Crossing Y		Name: DQ_34_1066_ISSO_PD@Typ Type: Crossing Y	
х	Y	х	Y
1.500000e+000	3.697962e-002	0.000000e+000	3.713536e-002

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[ISSO PU] Data



Name: DQ_34_1066_Pullup@Typ Type: Crossing Y		Name: DQ_34_1066_ISSO_PU@Typ Type: Crossing Y	
х	Y	х	Y
1.500000e+000	-3.012817e-002	0.000000e+000	-3.016485e-002

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[ISSO PU] & [ISSO PD] data in IBISCHK5

- IBISCHK5 checks that Isso_pd(0)=Ipd(Vcc) and Isso_pu(0)=Ipu(Vcc).
 - Pulldown is 0.42% different, Pullup is 0.12% different (typ).
 - ► IBISCHK5 issues a WARNING. Is it too sensitive?
 - WARNING Model DQ_34_1066: Minimum ISSO_PD current (0.031A) at 0V does not match Pulldown current (0.031A) at reference (1.425V)
- IBISCHK5 checks that Isso_pd(Vcc)=0 and Isso_pu(Vcc)=0.
 - Should a value of X nA cause a WARNING?
 - WARNING Model DQ_34_1066: Minimum ISSO_PD current (-0.000A) at Pullup reference (1.425V) - table value (1.425V) is non-zero
 - Note that the number of significant digits reported in the WARNING messages are not enough to indicate a problem.

Using [ISSO PU] & [ISSO PD] data

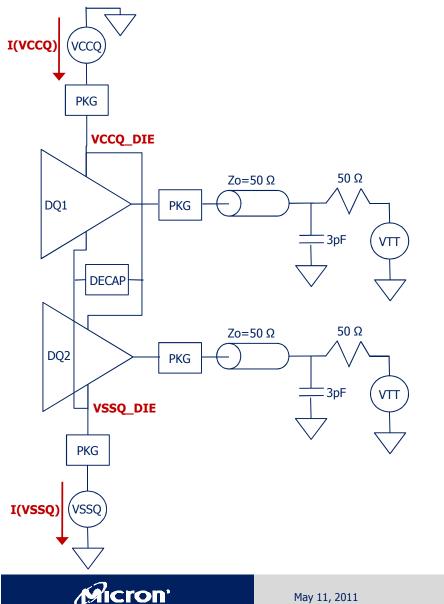
- Modulation coefficients can be calculated from the data (Ksso_pu & Ksso_pd).
 - What is the Ksso_pu value for a 50mV drop in Vcc?
 - Ksso_pu(Vtable_pu) = Isso_pu(Vtable_pu)/Isso_pu(0)
 - Ksso_pu(50mV) = Isso_pu(50mV)/Isso_pu(0)
 - Ksso_pu = -28.1067mA/-30.16485mA = 0.9318
 - What is the Ksso_pd value for a 50mV rise in Vss?
 - Ksso_pd(Vtable_pd) = Isso_pd(Vtable_pd)/Isso_pd(0)
 - Ksso_pd(50mV) = Isso_pd(50mV)/Isso_pd(0)
 - Ksso_pd = 34.83905mA/37.13536mA = **0.9382**
 - For this example, a 50mV drop in supply voltage translates to a ~7% reduction in the K scale factor.

Simulation Results

Comparing Tools A & B

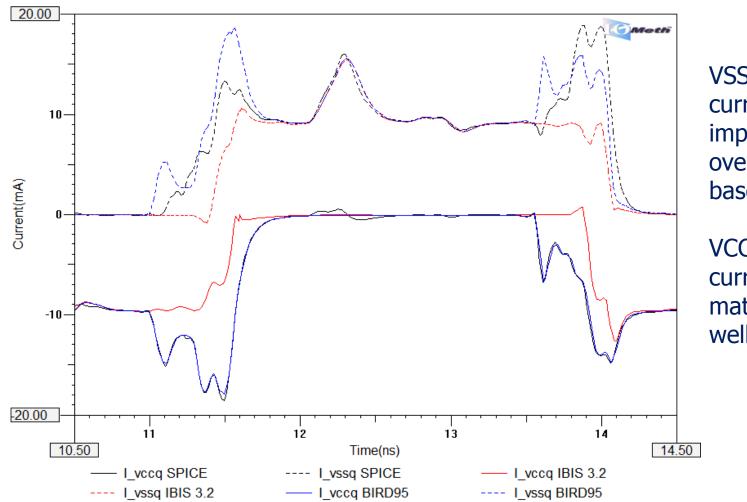


Simulation Setups



- PRBS pattern, minimum bit width of 1.25ns.
- Typical corner only.
- On-die decoupling capacitance included.
 - No method to properly include through IBIS syntax (Series models attach to Pins, not die).
 - Sim 1: DQ1 only, no package model
 - Compares BIRD95 directly to SPICE.
 - Sim 2: DQ1 only, Rpkg = 5 Ω
 - ► Tests BIRD98 current scaling.
 - Sim 3: DQ1 + DQ2 (in tri-state) with 8-port SPICE coupled package model
 - What happens with real package RLCs?
- Sim 4: DQ1 + DQ2 (with different PRBS) with SPICE package model
 - What happens with more than one buffer (real SSO conditions)?

Sim 1, Tool A



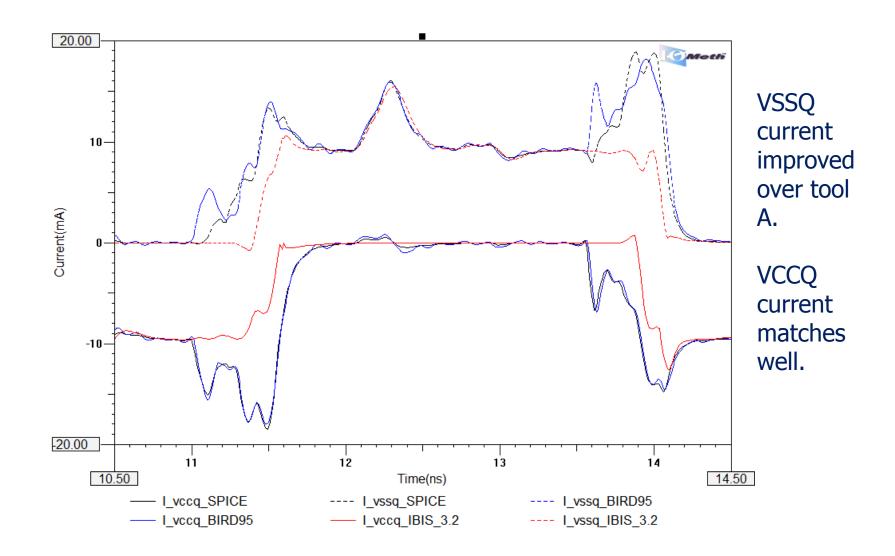
VSSQ current improved over baseline.

VCCQ current matches well.

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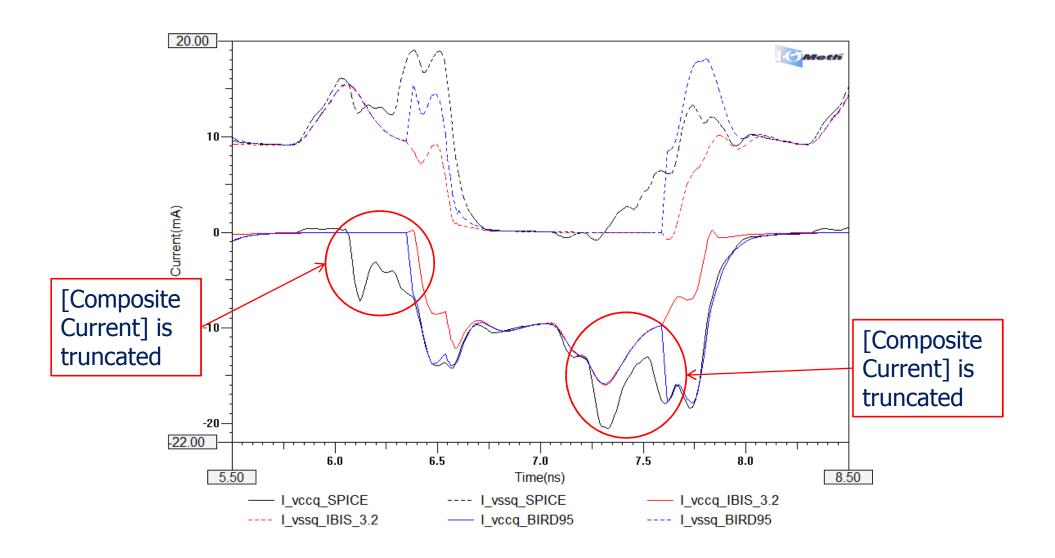
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Sim 1, Tool B



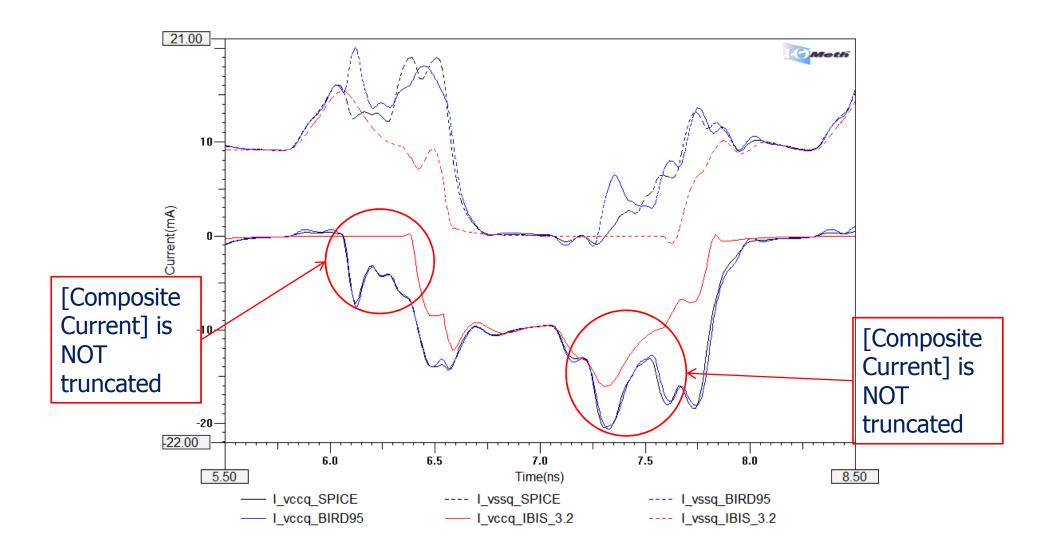
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Sim 1, Tool A, 1.25ns Bit Width

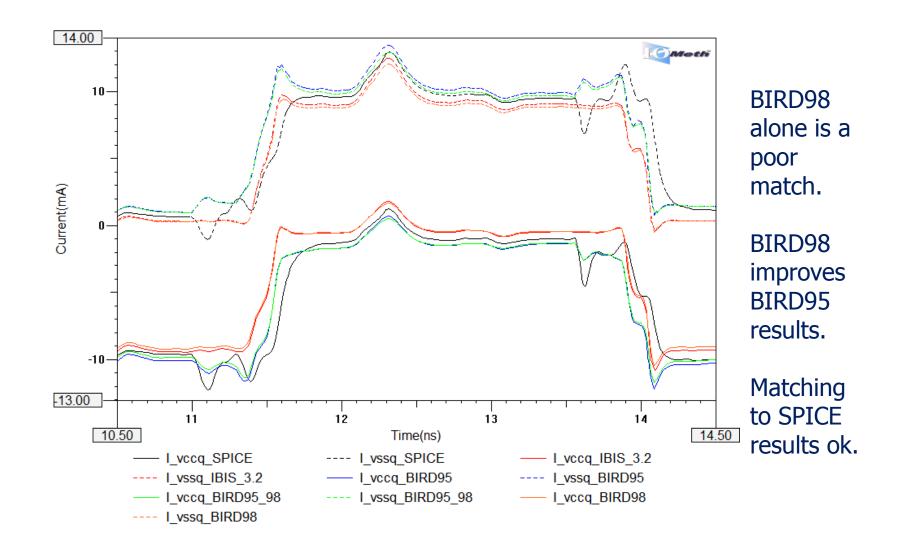


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Sim 1, Tool B, 1.25ns Bit Width

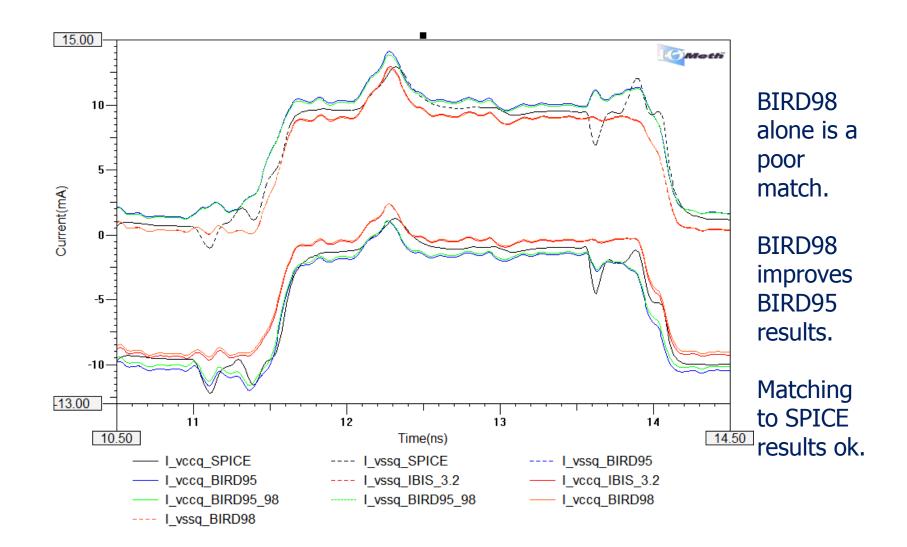


Sim 2, Tool A

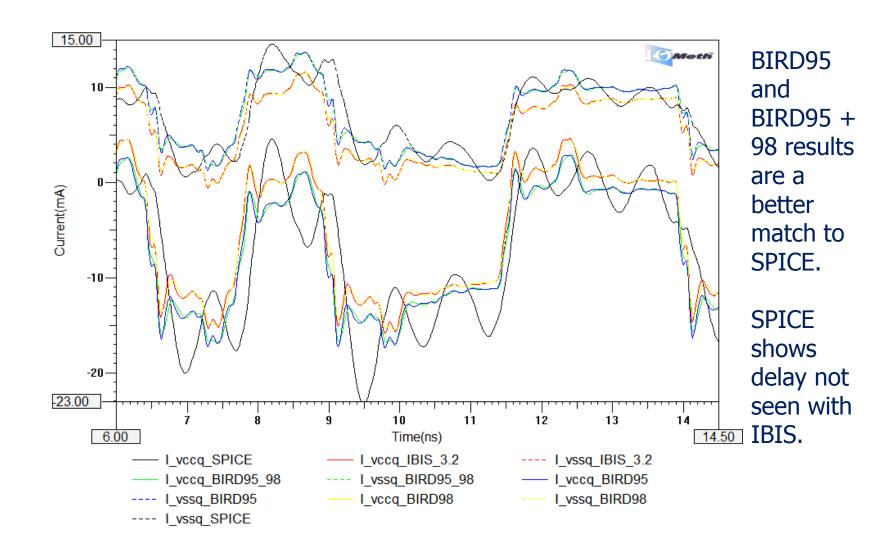


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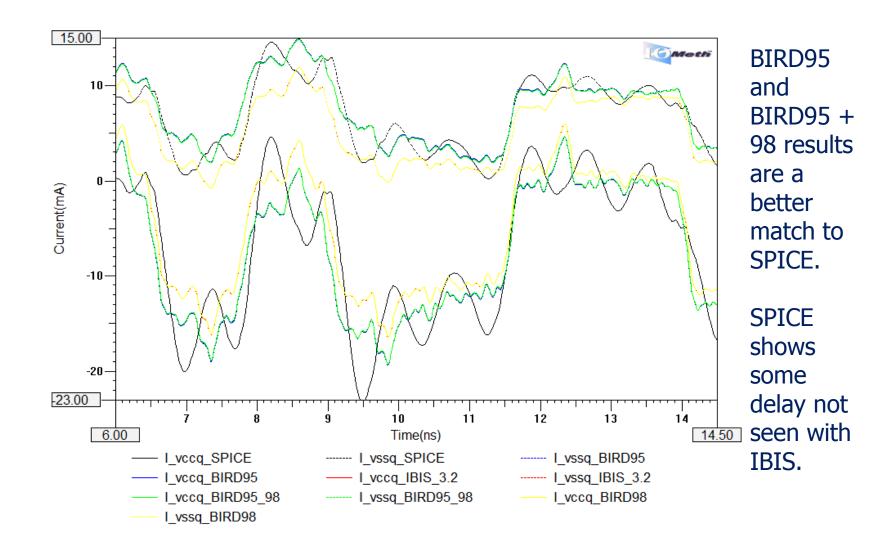
Sim 2, Tool B



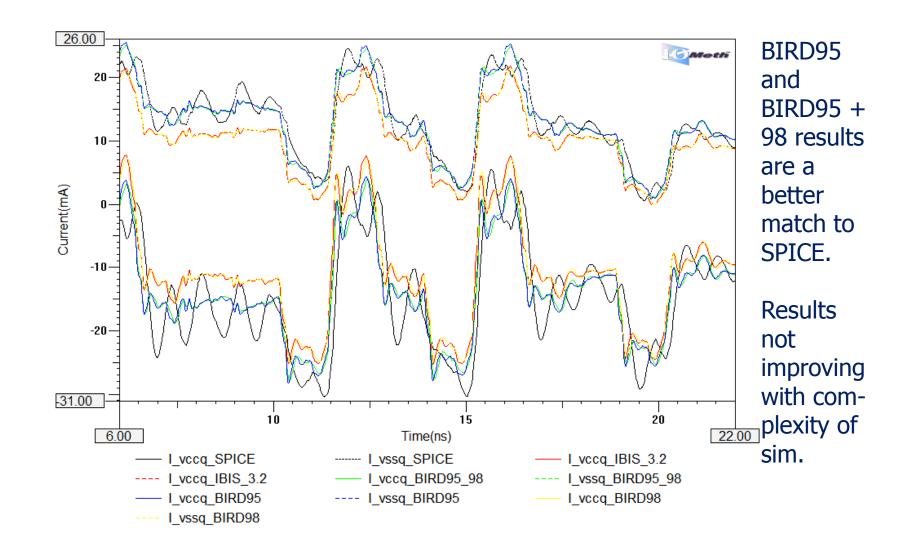
Sim 3, Tool A



Sim 3, Tool B

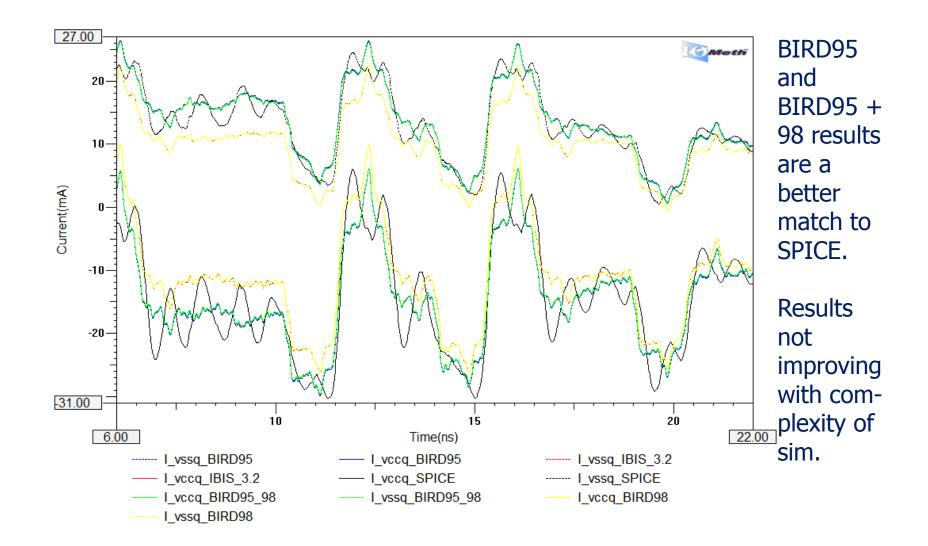


Sim 4, Tool A





Sim 4, Tool B



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Conclusions

- Implementations of BIRD95 significantly improve power supply current simulation accuracy.
- Implementations of BIRD98 improve upon accuracy of BIRD95 alone.
- BIRD98 without BIRD95 does not improve results for these test cases.
- Algorithms could use further improvement to better match SPICE simulations that include package parasitics.
- IBISCHK5 may be too 'sensitive' for BIRD98 checks.

